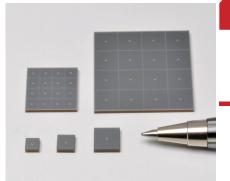


PHOTON IS OUR BUSINES:

# MPPC® (Multi-Pixel Photon Counter)



S14160/S14161 series

# Low breakdown voltage type MPPC for scintillation detector

The S14160/S14161 series achieve higher PDE (photon detection efficiency) and lower operation voltage than other MPPC to adapt for PET and radiation monitor application. They achieve small dead space in a photosensitive area with HWB (hole wire bonding) technology (Patent pending). And the gap from the photosensitive area edge to the package edge is only 0.2 mm. This package realizes the four-side buttable arrangement.

### Features

- ➡ Higher PDE (50% at λp, Vop=VBR + 2.7 V)
- Lower voltage (VBR=38 V typ.) operation
- **→** Small dead space in photosensitive area
- **■** Low afterpulses and crosstalk
- **→** High gain: 10<sup>6</sup> order
- **Excellent time resolution**
- Immune to effects of magnetic fields

### - Applications

- **PET** (positron emission tomography)
- **■** Radiation monitor

### Structure

Typ. no.	Number of channels (ch)	Effective photosensitive area/channel (mm²)	Pixel pitch (µm)	Number of pixels/channel	Package	Window	Window refractive index	Geometrical fill factor (%)
S14160-3050HS		$3.0 \times 3.0$		3531				
S14160-4050HS	1	$4.0 \times 4.0$		6331				
S14160-6050HS		$6.0 \times 6.0$		14331	Surface mount type	Silicone	1.57	
S14161-3050HS-04	16 (4 × 4)	$3.0 \times 3.0$	50	3531				74
S14161-3050HS-08	64 (8 × 8)	$3.0 \times 3.0$		3531	mount type			
S14161-4050HS-06	36 (6 × 6)	$4.0 \times 4.0$		6331				
S14161-6050HS-04	16 (4 × 4)	$6.0 \times 6.0$		14331				

### Absolute maximum ratings

Parameter	Symbol	Specification	Unit
Operating temperature*1	Topr	-40 to +85	°C
Storage temperature*1	Tstg	-40 to +85	°C
Soldering temperature*2	Tsol	240 (3 times)	°C

<sup>\*1:</sup> No dew condensation

When there is a temperature difference between a product and the surrounding area in high humidity environment, dew condensation may occur on the product surface. Dew condensation may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

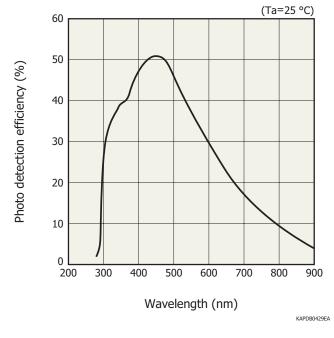
<sup>\*2:</sup> Reflow soldering, JEDEC J-STD-020 MSL 5a, see P.10

### **■** Electrical and optical characteristics (Typ. Ta=25 °C, Vover=2.7 V, unless otherwise noted)

Parameter		Symbol	S14160/S14161 -3050HS-04, -08	S14160/S14161 -4050HS-06	S14160/S14161 -6050HS-04	unit					
Spectral response range		λ		270 to 900		nm					
Peak sensitivity wavelength		λр		nm							
Photon detection efficiency a	at λp*3	PDE		%							
Breakdown voltage		VBR		V							
Recommended operating vo	ltage*4	Vop		V							
Vop variation between	Тур.			0.1							
channels in one product*5	Max.	_		V							
Dark current	Тур.	ID	0.6	0.6 1.1							
Dark current	Max.	10	1.8	7.5	μΑ						
Crosstalk probability		-		7		%					
Terminal capacitance		Ct	500	900	2000	pF					
Gain		М		-							
Temperature coefficient of recommended reverse voltage	ge	ΔTVop		mV/°C							

<sup>\*3:</sup> Photon detection efficiency does not include crosstalk and afterpulses.

### - Photon detection efficiency vs. wavelength (typical example)

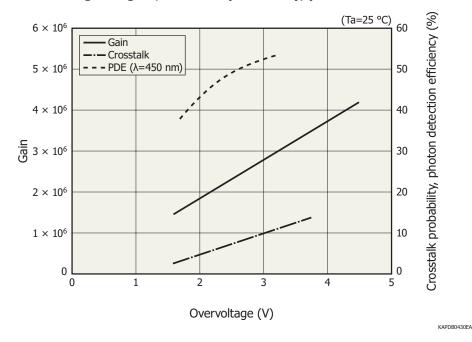


Photon detection efficiency does not include crosstalk and afterpulses.

<sup>\*4:</sup> Refer to the data attached for each product.

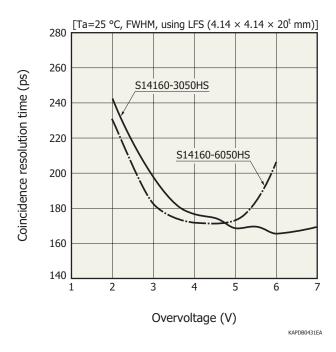
<sup>\*5:</sup> The parameter is for the S14161 series (multichannel type)

### Overvoltage vs. gain, crosstalk probability, photon detection efficiency (typical example)



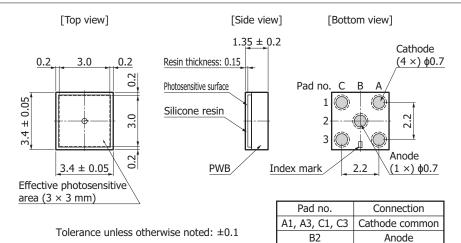
MPPC characteristics vary with the operating voltage. Although increasing the operating voltage improves the photon detection efficiency and time resolution, it also increases the dark count and crosstalk at the same time, so an optimum operating voltage must be selected to match the application.

### Coincidence resolution time vs. overvoltage (typical example)



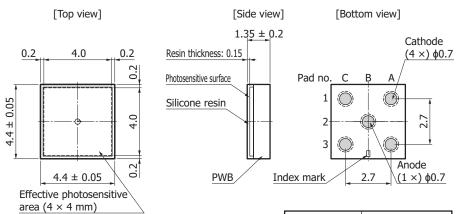
### Dimensional outlines (unit: mm)

### S14160-3050HS



KAPDA0195EA

### S14160-4050HS

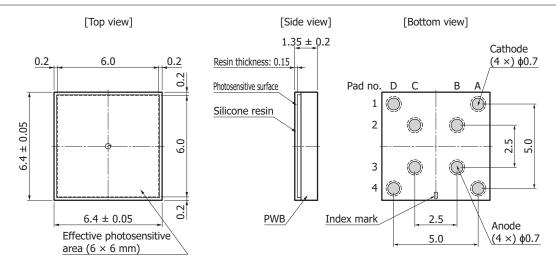


Tolerance unless otherwise noted: ±0.1

Pad no.	Connection
A1, A3, C1, C3	Cathode common
B2	Anode

KAPDA0196EA

### S14160-6050HS

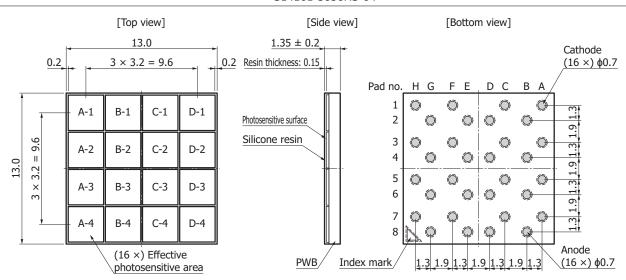


Tolerance unless otherwise noted: ±0.1

Pad no.	Connection
A1, A4, D1, D4	Cathode common
B2, B3, C2, C3	Anode common

KAPDA0197EA

### S14161-3050HS-04



Tolerance unless otherwise noted: ±0.1

KAPDA0198EA

Pad no.	Connection														
H1	A(D-1)	-	-	F1	A(C-1)	-	-	-	-	C1	K(B-1)	-	-	A1	K(A-1)
-	-	G2	K(D-1)	-	-	E2	K(C-1)	D2	A(B-1)	-	-	B2	A(A-1)	-	-
H3	A(D-2)	-	-	F3	A(C-2)	-	-	-	-	C3	K(B-2)	-	-	А3	K(A-2)
-	-	G4	K(D-2)	-	-	E4	K(C-2)	D4	A(B-2)	-	-	B4	A(A-2)	-	-
H5	A(D-3)	-	-	F5	A(C-3)	-	-	-	-	C5	K(B-3)	-	-	A5	K(A-3)
-	-	G6	K(D-3)	-	-	E6	K(C-3)	D6	A(B-3)	-	-	B6	A(A-3)	-	-
H7	A(D-4)	-	-	F7	A(C-4)	-	-	-	-	C7	K(B-4)	-	-	A7	K(A-4)
-	-	G8	K(D-4)	-	-	E8	K(C-4)	D8	A(B-4)	-	-	B8	A(A-4)	-	-



#### S14161-3050HS-08 [Top view] [Side view] [Bottom view] $1.35 \pm 0.2$ Anode (64 ×) \$0.7 25.8 0.2 $7 \times 3.2 = 22.4$ 0.2 Resin thickness: 0.15 Cathode (64 ×) $\phi$ 0.7 0.2 Photosensitive surface E-1 F-1 G-1 Silicone resin B-2 D-2 E-2 F-2 G-2 H-2 B-3 C-3 D-3 E-3 F-3 G-3 B-4 E-4 F-4 G-4 A-5 B-5 C-5 D-5 E-5 F-5 G-5 F-6 A-6 B-6 C-6 D-6 E-6 G-6 E-7 F-7 G-7 B-7 C-7 D-7 B-8 C-8 E-8 F-8 G-8 Index (64 ×) Effective PWB, mark photosensitive area

Tolerance unless otherwise noted: ±0.1

KAPDA0199E

Pad no.	Connection														
T1	A(H-1)	-	-	P1	A(G-1)	-	-	-	-	L1	K(F-1)	-	-	J1	K(E-1)
-	-	R2	K(H-1)	-	-	N2	K(G-1)	M2	A(F-1)	-	1	K2	A(E-1)	-	-
T3	A(H-2)	-	-	P3	A(G-2)	-	-	-	-	L3	K(F-2)	-	•	J3	K(E-2)
-	-	R4	K(H-2)	-	-	N4	K(G-2)	M4	A(F-2)	-	ı	K4	A(E-2)	-	-
T5	A(H-3)	-	-	P5	A(G-3)	-	-	-	-	L5	K(F-3)	-	•	J5	K(E-3)
-	-	R6	K(H-3)	-	-	N6	K(G-3)	M6	A(F-3)	-	ı	K6	A(E-3)	-	-
T7	A(H-4)	-	-	P7	A(G-4)	-	-	-	-	L7	K(F-4)	-	•	J7	K(E-4)
-	-	R8	K(H-4)	-	-	N8	K(G-4)	M8	A(F-4)	-	-	K8	A(E-4)	-	-
T9	A(H-5)	-	-	P9	A(G-5)	-	ı	-	-	L9	K(F-5)	-	ı	J9	K(E-5)
-	-	R10	K(H-5)	-	-	N10	K(G-5)	M10	A(F-5)	-	-	K10	A(E-5)	-	-
T11	A(H-6)	-	-	P11	A(G-6)	-	-	-	-	L11	K(F-6)	-	•	J11	K(E-6)
-	-	R12	K(H-6)	-	•	N12	K(G-6)	M12	A(F-6)	-	ı	K12	A(E-6)	-	-
T13	A(H-7)	-	-	P13	A(G-7)	-	ı	-	-	L13	K(F-7)	-	ı	J13	K(E-7)
-	-	R14	K(H-7)	-	-	N14	K(G-7)	M14	A(F-7)	-	-	K14	A(E-7)	-	-
T15	A(H-8)	-	-	P15	A(G-8)	-	-	-	-	L15	K(F-8)	-	-	J15	K(E-8)
-	-	R16	K(H-8)	-	-	N16	K(G-8)	M16	A(F-8)	-	-	K16	A(E-8)	-	-

Pad no.	Connection														
H1	A(D-1)	-	-	F1	A(C-1)	-	-	-	-	C1	K(B-1)	-	-	A1	K(A-1)
-	-	G2	K(D-1)	-	-	E2	K(C-1)	D2	A(B-1)	-	-	B2	A(A-1)	-	-
H3	A(D-2)	-	-	F3	A(C-2)	-	-	-	-	C3	K(B-2)	-	-	А3	K(A-2)
-	-	G4	K(D-2)	-	-	E4	K(C-2)	D4	A(B-2)	-	-	B4	A(A-2)	-	-
H5	A(D-3)	-	-	F5	A(C-3)	-	-	-	-	C5	K(B-3)	-	-	A5	K(A-3)
-	-	G6	K(D-3)	-	-	E6	K(C-3)	D6	A(B-3)	-	-	В6	A(A-3)	-	-
H7	A(D-4)	-	-	F7	A(C-4)	-	-	-	-	C7	K(B-4)	-	-	A7	K(A-4)
-	-	G8	K(D-4)	-	-	E8	K(C-4)	D8	A(B-4)	-	-	B8	A(A-4)	-	-
H9	A(D-5)	-	-	F9	A(C-5)	-	-	-	-	C9	K(B-5)	-	-	A9	K(A-5)
-	-	G10	K(D-5)	-	-	E10	K(C-5)	D10	A(B-5)	-	-	B10	A(A-5)	-	-
H11	A(D-6)	-	-	F11	A(C-6)	-	-	-	-	C11	K(B-6)	-	-	A11	K(A-6)
-	-	G12	K(D-6)	-	-	E12	K(C-6)	D12	A(B-6)	-	-	B12	A(A-6)	-	-
H13	A(D-7)	-	-	F13	A(C-7)	-	-	-	-	C13	K(B-7)	-	-	A13	K(A-7)
-	-	G14	K(D-7)	-	-	E14	K(C-7)	D14	A(B-7)	-	-	B14	A(A-7)	-	-
H15	A(D-8)	-	-	F15	A(C-8)	-	-	-	-	C15	K(B-8)	-	-	A15	K(A-8)
-	-	G16	K(D-8)	-	-	E16	K(C-8)	D16	A(B-8)	-	-	B16	A(A-8)	-	-



#### S14161-4050HS-06 [Top view] [Side view] [Bottom view] 25.4 $1.35 \pm 0.2$ 0.2 $5 \times 4.2 = 21.0$ 0.2 Resin thickness: 0.15 Index mark 0.2 Photosensitive surface D-1 E-1 F-1 B-1 C-1 2.12.1 Silicone resin B-2 C-2 D-2 E-2 F-2 A-2 = 23.1A-3 B-3 C-3 D-3 E-3 F-3 25.4 $5 \times 4.2 =$ C-4 B-4 D-4 E-4 A-5 B-5 C-5 D-5 E-5 F-5 10 11 00 B-6 C-6 D-6 E-6 00 (36 ×) Effective PWB photosensitive area $11 \times 2.1 = 23.1$ Tolerance unless otherwise noted: ±0.1 Cathode (36 $\times$ ) $\phi$ 1.0/ Anode (36 ×) \$1.0

KAPDA0200EA

Pad no.	Connection										
-	-	L1	A(F-1)	-	-	J1	A(E-1)	H1	K(D-1)	-	-
M2	K(F-1)	-	-	K2	K(E-1)	-	-	-	-	G2	A(D-1)
-	-	L3	A(F-2)	-	-	J3	A(E-2)	H3	K(D-2)	-	-
M4	K(F-2)	-	-	K4	K(E-2)	-	-	-	-	G4	A(D-2)
-	-	L5	A(F-3)	-	-	J5	A(E-3)	H5	K(D-3)	-	-
M6	K(F-3)	-	-	K6	K(E-3)	-	-	-	-	G6	A(D-3)
-	-	L7	A(F-4)	-	-	J7	A(E-4)	H7	K(D-4)	-	-
M8	K(F-4)	-	-	K8	K(E-4)	-	-	-	-	G8	A(D-4)
-	-	L9	A(F-5)	-	-	Ј9	A(E-5)	H9	K(D-5)	-	-
M10	K(F-5)	-	-	K10	K(E-5)	-	-	-	-	G10	A(D-5)
-	-	L11	A(F-6)	-	-	J11	A(E-6)	H11	K(D-6)	-	-
M12	K(F-6)	-	-	K12	K(E-6)	-	-	-	-	G12	A(D-6)

Pad no.	Connection										
-	-	E1	A(C-1)	D1	K(B-1)	-	-	B1	K(A-1)	-	-
F2	K(C-1)	-	-	-	-	C2	A(B-1)	-	-	A2	A(A-1)
-	-	E3	A(C-2)	D3	K(B-2)	-	-	В3	K(A-2)	-	-
F4	K(C-2)	-	-	-	-	C4	A(B-2)	-	-	A4	A(A-2)
-	-	E5	A(C-3)	D5	K(B-3)	-	-	B5	K(A-3)	-	-
F6	K(C-3)	-	-	-	-	C6	A(B-3)	-	-	A6	A(A-3)
-	-	E7	A(C-4)	D7	K(B-4)	-	-	В7	K(A-4)	-	-
F8	K(C-4)	-	-	-	-	C8	A(B-4)	-	-	A8	A(A-4)
-	-	E9	A(C-5)	D9	K(B-5)	-	-	В9	K(A-5)	-	-
F10	K(C-5)	-	-	-	-	C10	A(B-5)	-	-	A10	A(A-5)
-	-	E11	A(C-6)	D11	K(B-6)	-	-	B11	K(A-6)	-	-
F12	K(C-6)	-	-	-	-	C12	A(B-6)	-	-	A12	A(A-6)

#### S14161-6050HS-04 [Top view] [side view] [Bottom view] 25.0 $1.35 \pm 0.2$ 0.2 $3 \times 6.2 = 18.6$ 0.2 Resin thickness: 0.15 Index mark Pad no. Н G E D (<u>Ô</u>) (<u>Ô</u>) (<u>(</u>) 1 Photosensitive surface C-1 D-1 B-1 3.1 A-1 2 (<u>Ö</u>) (<u>O</u>) (<u>Ö</u>) Silicone resin 3 (<u>Ö</u>) (<u>Ô</u>) A-2 B-2 C-2 D-2 4 (<u>Ö</u>) (<u>Ô</u>) (<u>Ô</u>) 25.0 3 × 6.2 : 5 (<u>O</u>) A-3 B-3 C-3 D-3 6 (<u>O</u>) (<u>)</u> (<u>Ô</u>) 7 (<u>Ô</u>) (<u>O</u>) A-4 B-4 C-4 D-4 8 (<u>(</u>) 0.2 (16 ×) Effective 3.1 3.1 Anode (16 ×) \$1.0 photosensitive area PWB. $7 \times 3.1 = 21.7$ Cathode (16 $\times$ ) $\phi$ 1.0

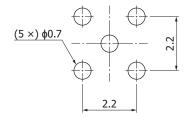
Tolerance unless otherwise noted: ±0.1

KAPDA0201EA

Pad no.	Connection														
-	-	G1	A(D-1)	-	-	E1	A(C-1)	D1	K(B-1)	-	-	B1	K(A-1)	-	-
H2	K(D-1)	-	-	F2	K(C-1)	-	-	-	-	C2	A(B-1)	-	-	A2	A(A-1)
-	-	G3	A(D-2)	-	-	E3	A(C-2)	D3	K(B-2)	-	-	В3	K(A-2)	-	-
H4	K(D-2)	-	-	F4	K(C-2)	-	-	-	-	C4	A(B-2)	-	-	A4	A(A-2)
-	-	G5	A(D-3)	-	-	E5	A(C-3)	D5	K(B-3)	-	-	B5	K(A-3)	-	-
H6	K(D-3)	-	-	F6	K(C-3)	-	-	-	-	C6	A(B-3)	-	-	A6	A(A-3)
-	-	G7	A(D-4)	-	-	E7	A(C-4)	D7	K(B-4)	-	-	B7	K(A-4)	-	-
H8	K(D-4)	-	-	F8	K(C-4)	-	-	-	-	C8	A(B-4)	-	-	A8	A(A-4)

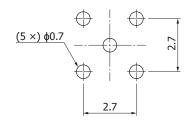
### - Recommended land pattern (unit: mm)

### S14160-3050HS



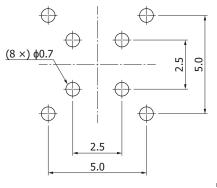
KAPDC0108EA

### S14160-4050HS



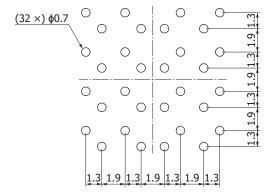
KAPDC0109EA

### S14160-6050HS



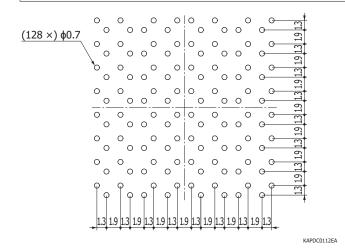
KAPDC0110EA

### S14161-3050HS-04

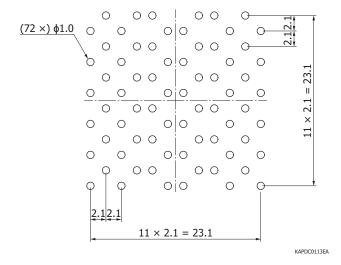


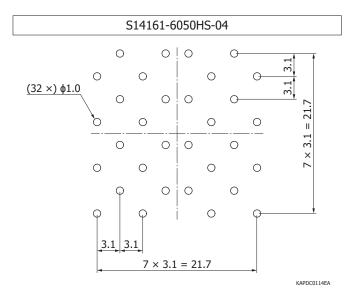
KAPDC0111EA

### S14161-3050HS-08

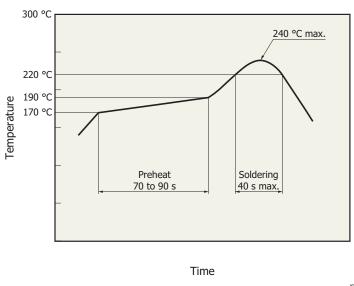


### S14161-4050HS-06





### Recommended reflow soldering conditions



KPICB0171EA

- This surface mount type package product supports lead-free soldering. After unpacking, store it in an environment at a temperature of 25 °C or less and a humidity of 60% or less, and perform soldering within 24 hours.
- The effect that the product is subject to during reflow soldering varies depending on the circuit board and reflow furnace that are used. Before actual reflow soldering, check for any problems by testing out the reflow soldering methods in advance.
- · When three or more mounths have passed or if the packing bag has not been stored in an environment described above, perform baking. For the baking method, see the related information "Surface mount type products" precautions.

### **MPPC (Multi-Pixel Photon Counter)**

S14160/S14161 series

### Precautions

· If necessary, incorporate appropriate protective circuits in power supplies, devices, and measuring instruments to prevent overvoltage and overcurrent.

### Related information

www.hamamatsu.com/sp/ssd/doc\_en.html

- Precautions
- Disclaimer
- · Surface mount type products
- Technical information
- · MPPC

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The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

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